50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

19 February 2024

Product data sheet

1. General description

PNP Resistor-Equipped Transistor (RET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTC114EMB

2. Features and benefits

- 100 mA output current capability
- · Reduces component count
- Built-in bias transistors
- · Reduces pick and place costs
- Simplifies circuit design
- Leadless ultra small SMD plastic package
- Low package height of 0.37 mm
- AEC-Q101 qualified

3. Applications

- Low-current peripheral driver
- · Replaces general-purpose transistors in digital applications
- Control of IC inputs
- Mobile applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)	T _{amb} = 25 °C	7	10	13	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)		
2	G	GND (emitter)	3	
3	0	output (collector)	1 2	R1
			Transparent	GND
			top view DFN1006B-3 (SOT883B)	sym003

6. Ordering information

Table 3. Ordering information

Type number Package					
	Name	Description	Version		
PDTA114EMB		plastic, leadless ultra small plastic package; 3 solder lands; 0.35 mm pitch; 1.0 mm x 0.6 mm x 0.37 mm body	<u>SOT883B</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code
PDTA114EMB	0001
	1001

8. Limiting values

Table 5. Limiting values

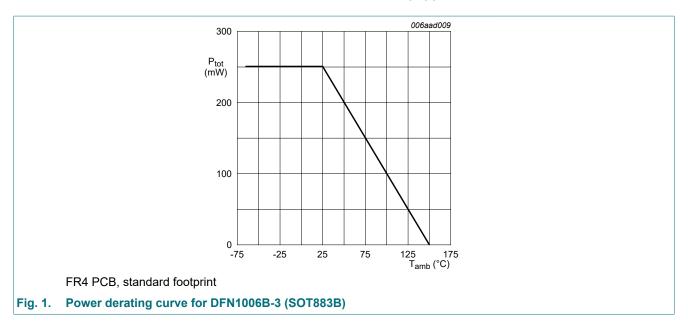
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V_{EBO}	emitter-base voltage	open collector		-	-10	V
V _I	input voltage			-40	10	V
Io	output current			-	-100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; pulsed		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

PDTA114EMB

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

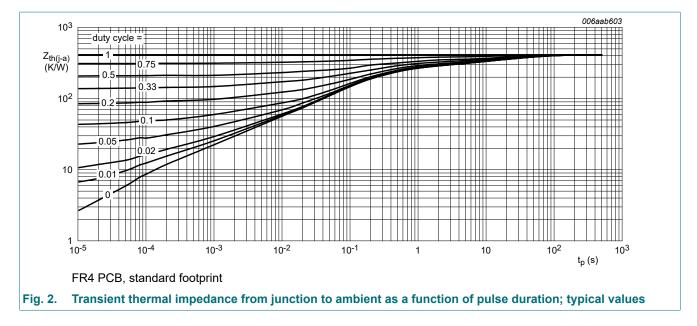


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



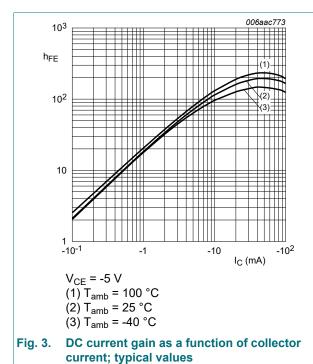
50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

10. Characteristics

Table 7. Characteristics

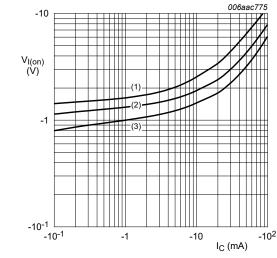
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-1	μΑ
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-400	μΑ
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -5 mA; T _{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-	-150	mV
V _{I(off)}	off-state input voltage	V_{CE} = -5 V; I_{C} = 100 μ A; T_{amb} = 25 °C		-	-1.1	-0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -10 mA; T_{amb} = 25 °C		-2.5	-1.8	-	V
R1	bias resistor 1 (input)	T _{amb} = 25 °C		7	10	13	kΩ
R2/R1	bias resistor ratio			0.8	1	1.2	
C _c	collector capacitance	V_{CB} = -10 V; I_E = 0 A; i_e = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[1]	-	180	-	MHz

[1] Characteristics of built-in transistor.



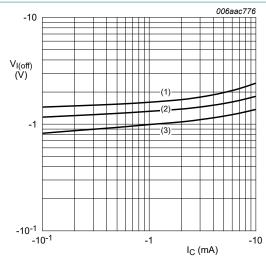
function of collector current; typical values

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω



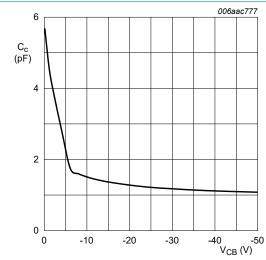
V_{CE} = -0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Fig. 5. On-state input voltage as a function of collector | Fig. 6. current; typical values



V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$

Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values

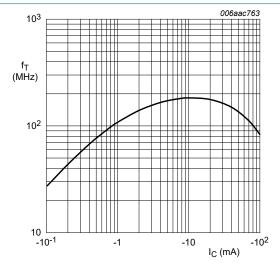


Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

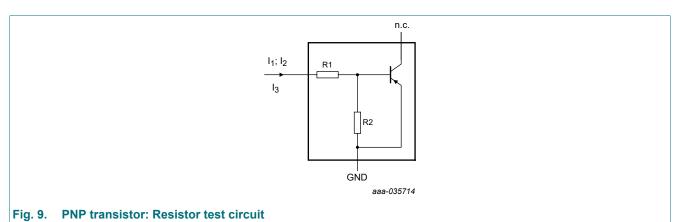
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I3)}{R1 \cdot I3} - 1$$



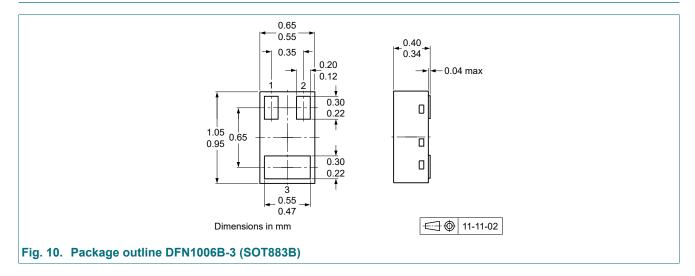
Resistor test conditions

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions		
			I ₁	l ₂	l ₃
PDTA114EMB	10	10	-350 μΑ	-450 μΑ	400 μΑ

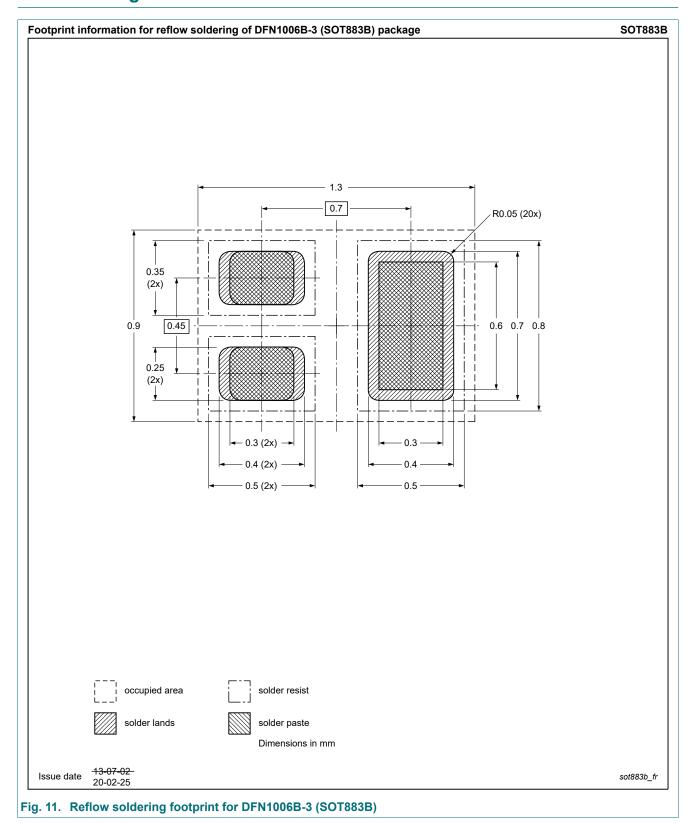
50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

12. Package outline



50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

13. Soldering



50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PDTA114EMB v.3	20240219	Product data sheet	-	PDTA114EMB v.2			
Modifications:	Pinning: Graphic syn	Pinning: Graphic symbol adjusted					
PDTA114EMB v.2	20230207	Product data sheet	-	PDTA114EMB v.1			
PDTA114EMB v.1	20120515	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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PDTA114EMB

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